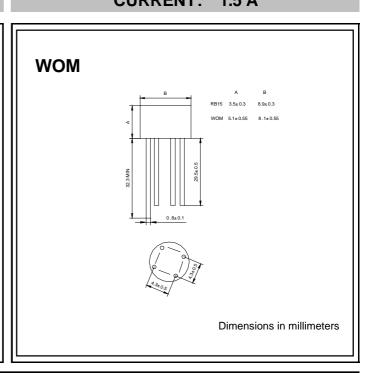
SILICON BRIDGE RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V CURRENT: 1.5 A

FEATURES

- Surge overload rating to 50 Amperes peak
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Plastic material has UL flammability recognition 94V-O
- ♦ Weight: 0.050 ounces,1.42 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

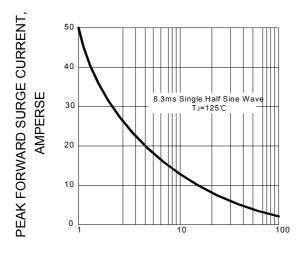
Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		W005L	W01L	W02L	W04L	W06L	W08L	W10L	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forw ard Output current @T _A =25°C	I _{F(AV)}	1.5						А	
Peak forw ard surge current 8.3ms single half-sine-wave superimposed on rated load	I _{FSM}	50.0							А
Maximum instantaneous forward voltage at 1.0 A	V _F	1.0							V
Maximum reverse current $@T_A = 25^{\circ}C$ at rated DC blocking voltage $@T_A = 100^{\circ}C$	I _R	5.0 0.5							μA mA
Operating junction temperature range	TJ	- 55 + 150							$^{\circ}$
Storage temperature range	T _{STG}	- 55 + 150							${\mathbb C}$

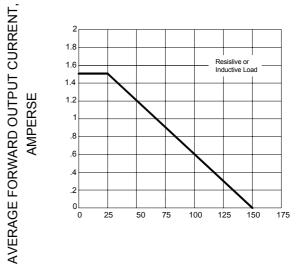
www.diode.kr

FIG.1 - PEAK FORWARD SURGE CURRENT



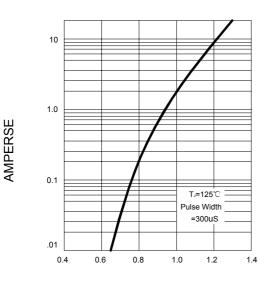
NUMBER OF CYCLES AT 60Hz

FIG.2 - FORWARD DERATING CURVE



AMBIENT TEMPERATURE, °C

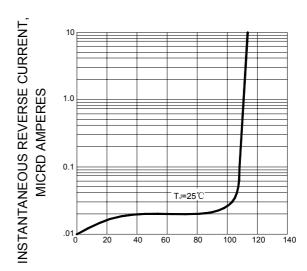
FIG.3 - TYPICAL FORWARD CHARACTERISTIC



INSTANTANEOUS FORWARD CURRENT,

INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.4 - TYPICAL REVERSE CHARACTERISTIC



PERCENT OF RATED PEAK REVERSE VOLTAGE